

SLPS257A - MARCH 2010 - REVISED SEPTEMBER 2010

30V N-Channel NexFET[™] Power MOSFET

Check for Samples: CSD17311Q5

FEATURES

- **Optimized for 5V Gate Drive**
- Ultra Low Q_a and Q_{ad}
- Low Thermal Resistance
- **Avalanche Rated**
- **Pb Free Terminal Plating**
- **RoHS Compliant**
- **Halogen Free**
- SON 5-mm × 6-mm Plastic Package

APPLICATIONS

- **Notebook Point-of-Load**
- Point-of-Load Synchronous Buck in Networking, Telecom and Computing Systems

DESCRIPTION

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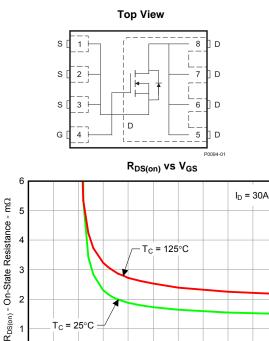
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T_C = 25°C

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1

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications and optimized for 5V gate drive applications.



T_C = 125°C

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V_{GS} - Gate-to-Source Voltage - V

7 8 9 10

PRODUCT SUMMARY

V _{DS}	Drain to Source Voltage 30			
Qg	Gate Charge Total (4.5V)	Gate Charge Total (4.5V) 24		
Q _{gd}	Gate Charge Gate to Drain	5.2	nC	
		$V_{GS} = 3V$	2.3	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 4.5V 1.8		mΩ
		V _{GS} = 8V 1.6		mΩ
V _{GS(th)}	Threshold Voltage 1.2			

ORDERING INFORMATION

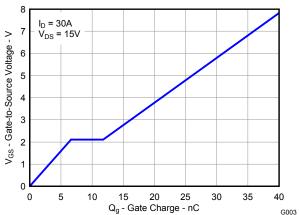
Device	Package	Media	Qty	Ship
CSD17311Q5	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

$T_A = 2$	5°C unless otherwise stated	VALUE	UNIT
V _{DS}	Drain to Source Voltage	30	V
V_{GS}	Gate to Source Voltage	+10 /8	V
	Continuous Drain Current, $T_C = 25^{\circ}C$	100	А
ID	Continuous Drain Current ⁽¹⁾	32	А
I _{DM}	Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$	200	А
PD	Power Dissipation ⁽¹⁾	3.2	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, Single Pulse $I_D = 113A$, L = 0.1mH, $R_G = 25\Omega$	638	mJ

(1) Typical $R_{\theta JA}$ = 40°C/W when mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.

(2) Pulse duration ≤300µs, duty cycle ≤2%



GATE CHARGE

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CSD17311Q5

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XAS STRUMENTS

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

$(T_A = 25^{\circ})$	°C unless otherwise stated)				
	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
Static Cl	haracteristics				
BV_{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250 \mu A$	30		V
I _{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = 24V$		1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +10/-8V$		100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.9 1.2	1.6	V
		$V_{GS} = 3V$, $I_D = 30A$	2.3	3.1	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 4.5V, I_D = 30A$	1.8	2.3	mΩ
		$V_{GS} = 8V, I_D = 30A$	1.6	2	mΩ
9 _{fs}	Transconductance	$V_{DS} = 15V, I_{D} = 30A$	200		S
Dynamic	Characteristics				
C _{iss}	Input Capacitance		3290	4280	pF
Coss	Output Capacitance	$V_{GS} = 0V, V_{DS} = 15V,$ f = 1MHz	1740	2260	pF
C _{rss}	Reverse Transfer Capacitance		85	110	pF
R _G	Series Gate Resistance		1.2	2.4	Ω
Qg	Gate Charge Total (4.5V)		24	31	nC
Q _{gd}	Gate Charge Gate to Drain	V _{DS} = 15V,	5.2		nC
Q_gs	Gate Charge Gate to Source	$I_{DS} = 30A$	6.6		nC
Q _{g(th)}	Gate Charge at Vth		3.9		nC
Q _{oss}	Output Charge	$V_{DS} = 14.8V, V_{GS} = 0V$	47		nC
t _{d(on)}	Turn On Delay Time		12		ns
t _r	Rise Time	V _{DS} = 15V, V _{GS} = 4.5V,	18		ns
t _{d(off)}	Turn Off Delay Time	$I_{DS} = 30A, R_G = 2\Omega$	33		ns
t _f	Fall Time		12		ns
Diode C	haracteristics				
V _{SD}	Diode Forward Voltage	$I_{SD} = 30A, V_{GS} = 0V$	0.85	1	V
Q _{rr}	Reverse Recovery Charge	V _{DD} = 14.8V, I _F = 30A,	74		nC
t _{rr}	Reverse Recovery Time	$di/dt = 300A/\mu s$	39		ns

THERMAL CHARACTERISTICS

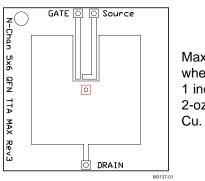
$(T_A = 25^{\circ}C \text{ unless otherwise stated})$								
	PARAMETER	MIN	TYP	MAX	UNIT			
R_{\thetaJC}	Thermal Resistance Junction to Case ⁽¹⁾			1	°C/W			
R_{\thetaJA}	Thermal Resistance Junction to Ambient ⁽¹⁾⁽²⁾			49	°C/W			

 $R_{ ext{BJC}}$ is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch × 1.5-inch (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. $R_{ ext{BJC}}$ is specified by design, whereas $R_{ ext{BJA}}$ is determined by the user's board design. Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu. (1)

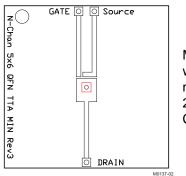
(2)







Max $R_{\theta JA} = 49^{\circ}C/W$ when mounted on 1 inch² (6.45 cm²) of 2-oz. (0.071-mm thick) Cu.



Max $R_{\theta,JA} = 120^{\circ}C/W$ when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

TYPICAL MOSFET CHARACTERISTICS

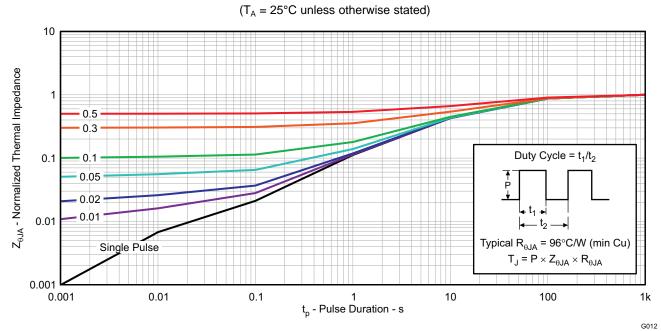


Figure 1. Transient Thermal Impedance

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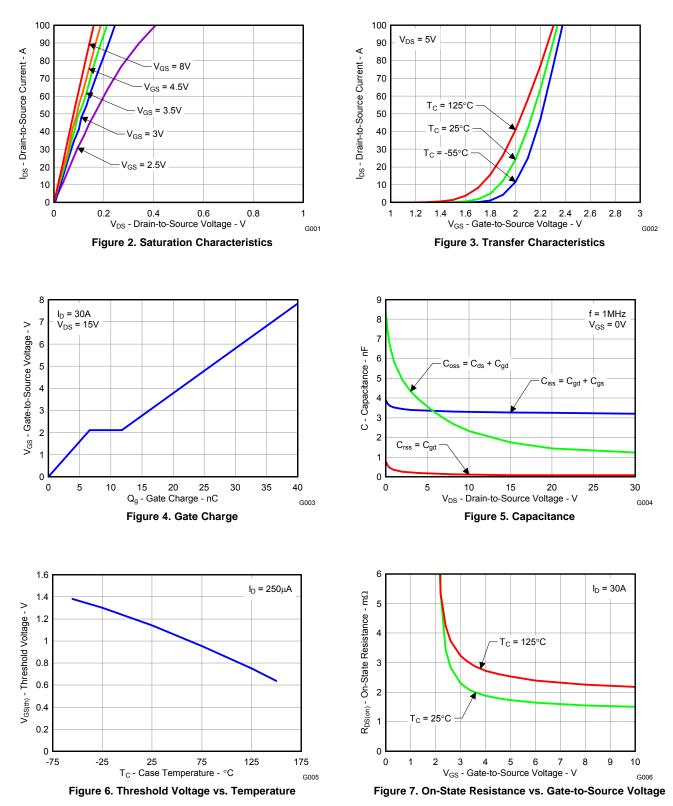
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ISTRUMENTS

EXAS

TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$





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TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

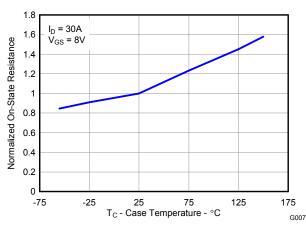
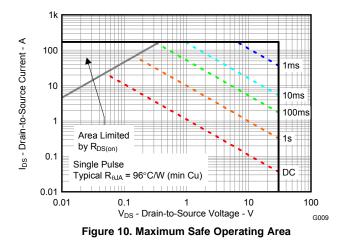


Figure 8. Normalized On-State Resistance vs. Temperature



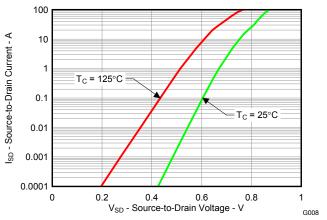


Figure 9. Typical Diode Forward Voltage

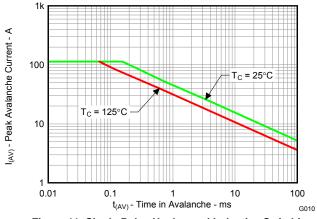


Figure 11. Single Pulse Unclamped Inductive Switching

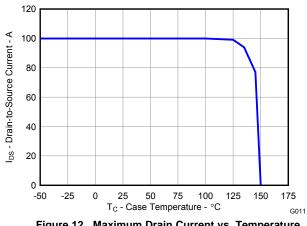


Figure 12. Maximum Drain Current vs. Temperature

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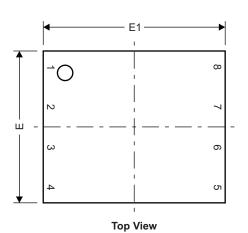
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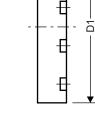
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MECHANICAL DATA

c1

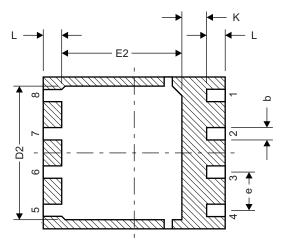
Q5 Package Dimensions



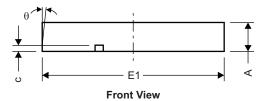


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Bottom View



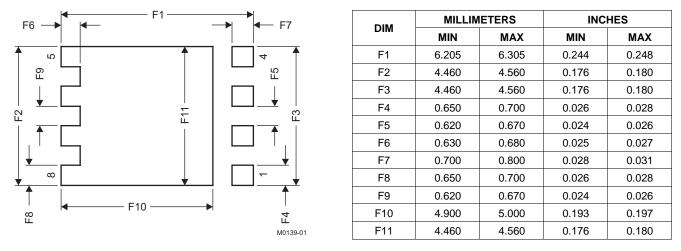
M0140-01

DIM	MILLIN	IETERS	INC	HES
DIN	MIN	MAX	MIN	MAX
А	0.950	1.050	0.037	0.039
b	0.360	0.460	0.014	0.018
С	0.150	0.250	0.006	0.010
c1	0.150	0.250	0.006	0.010
D1	4.900	5.100	0.193	0.201
D2	4.320	4.520	0.170	0.178
E	4.900	5.100	0.193	0.201
E1	5.900	6.100	0.232	0.240
E2	3.920	4.12	0.154	0.162
е	1.27	TYP	0.0	50
К	0.760		0.030	
L	0.510	0.710	0.020	0.028
θ	0.00			



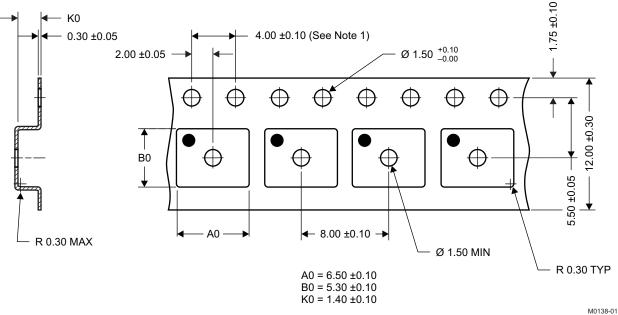
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Recommended PCB Pattern



For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

Q5 Tape and Reel Information



Notes: 1. 10-sprocket hole-pitch cumulative tolerance ±0.2

2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm

- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm, unless otherwise specified.
- 5. Thickness: 0.30 ±0.05mm
- 6. MSL1 260°C (IR and convection) PbF reflow compatible

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REVISION HISTORY

Cł	nanges from Original (March 2010) to Revision A	Page
•	Deleted the Package Marking Information section	7



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7-Jan-2016

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CSD17311Q5	ACTIVE	VSON-CLIP	DQH	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD17311	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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